PCP1405

Power MOSFET 250V, 6.5Ω, 0.6A, Single N-Channel



Features

- On-resistance $R_{DS}(on)1=5\Omega$ (typ)
- 2.5V drive
- Protection diode in
- Halogen free compliance

Specifications

Absolute Maximum Ratings at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Value	Unit
Drain to Source Voltage	VDSS		250	V
Gate to Source Voltage	VGSS		±10	V
Drain to Gate Voltage	VDGS		250	V
Gate to Drain Voltage	VGDS		±10	V
Drain Current (DC)	۱ _D		0.6	А
Drain Current (Pulse)	IDP	PW≤10µs, duty cycle≤1%	2.4	А
Power Dissipation		Tc=25°C	3.5	W
	PD	When mounted on ceramic substrate (600mm ² ×0.8mm)	1.3	W
Junction Temperature	Тј		150	°C
Storage Temperature	Tstg		- 55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Thermal Resistance Ratings

Parameter	Symbol	Value	Unit
Junction to Case Steady State	R _{θJC}	35.7	
Junction to Ambient	Pour	96.1	°C/W
When mounted on ceramic substrate (600mm ² ×0.8mm)	$R_{\theta JA}$	90.1	

Electrical Characteristics at Ta = 25°C

Decemeter			Value			
Parameter	Symbol	Conditions	min	typ	max	Unit
Drain to Source Breakdown Voltage	V(BR)DSS	I _D =1mA, V _{GS} =0V	250			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =250V, V _{GS} =0V			1	μA
Gate to Source Leakage Current	IGSS	V _{GS} =±8V, V _{DS} =0V			±10	μA
Gate Threshold Voltage	VGS(th)	V _{DS} =10V, I _D =1mA	0.4		1.3	V
Forward Transconductance	9FS	V _{DS} =10V, I _D =0.3A		1.4		S

Continued on next page.

ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

Parameter			Value		
Parameter	Symbol	Conditions	typ	max	Unit
Otatie Desig to Ocurre Or Otate Desigtation	R _{DS} (on)1	ID=0.3A, VGS=4.5V	5	6.5	Ω
Static Drain to Source On-State Resistance	R _{DS} (on)2	ID=0.3A, VGS=2.5V	5.1	7.2	Ω
Input Capacitance	Ciss		140		pF
Output Capacitance	Coss	V _{DS} =20V, f=1MHz	8		pF
Reverse Transfer Capacitance	Crss		3		pF
Turn-ON Delay Time	t _d (on)		7.6		ns
Rise Time	tr	See specified Test Circuit	7.8		ns
Turn-OFF Delay Time	t _d (off)		19		ns
Fall Time	tf		26		ns
Total Gate Charge	Qg		2.1		nC
Gate to Source Charge	Qgs	V _{DS} =125V, V _{GS} =4.5V, I _D =0.6A	0.3		nC
Gate to Drain "Miller" Charge	Qgd	7	0.7		nC
Forward Diode Voltage	V _{SD}	IS=0.6A, VGS=0V	0.84	1.2	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Ordering & Package Information

Device	Package	Shipping	note
PCP1405-TD-H	PCP, SC-62 SOT-89, TO-243	1,000 pcs. / reel	Pb-Free and Halogen Free

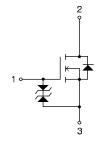
Packing Type:TD



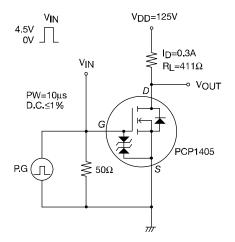


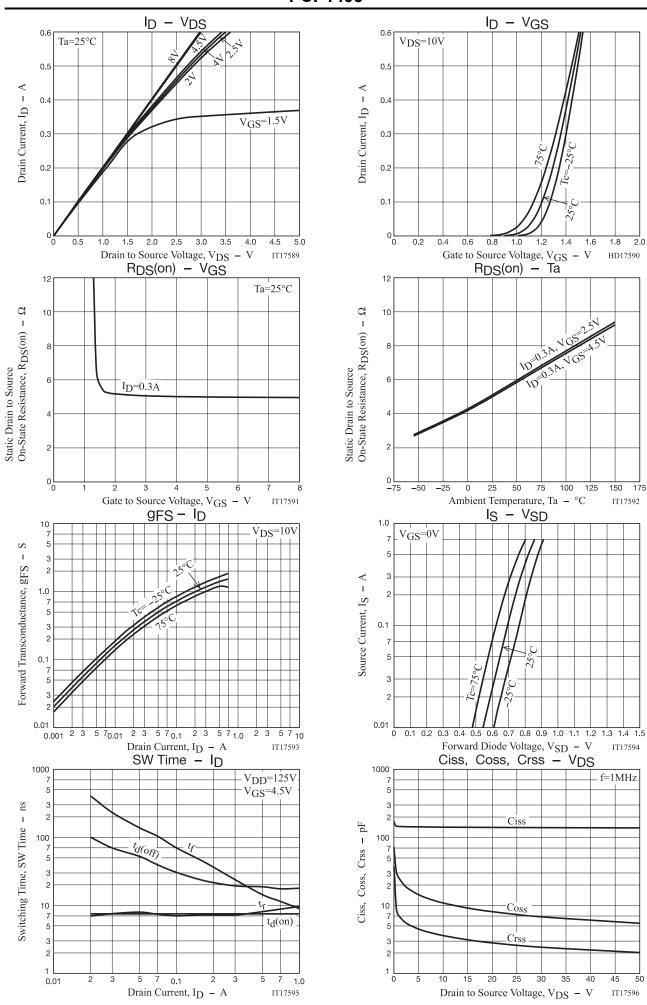


Electrical Connection



Switching Time Test Circuit





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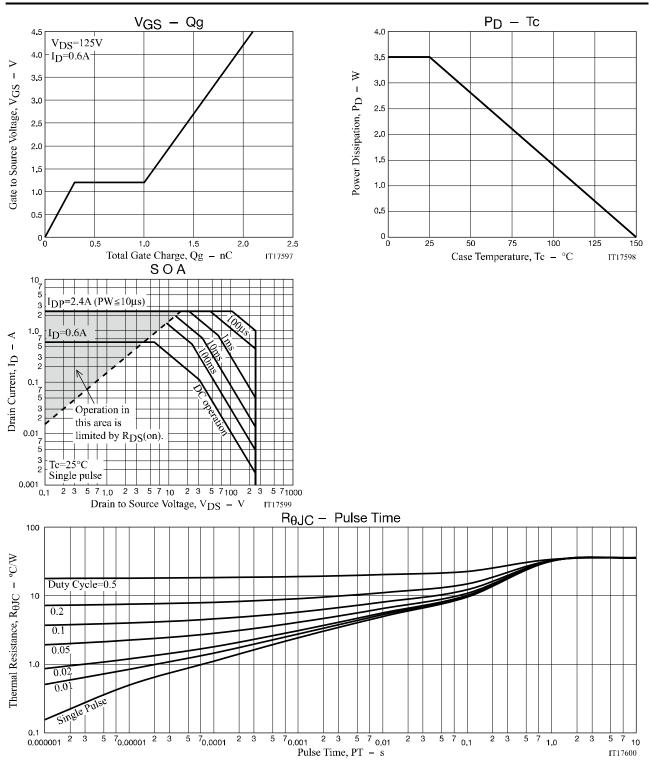
IT17596

50

1.8 2.0

150 175

IT17592



4. 5±0.1

Package Dimensions

РСР1405-TD-Н

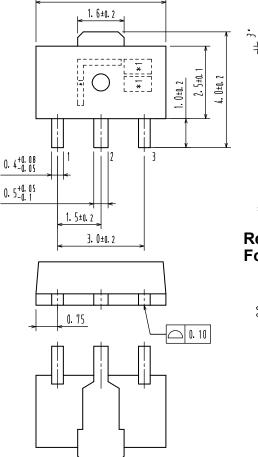
SOT-89/PCP-1

CASE 419AU ISSUE O unit : mm

1: Gate

2: Drain

3: Source

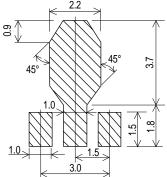


0. 4±0. 03

1. 5±0. 1

*1:Lot indication

Recommended Soldering Footprint



Note on usage : Since the PCP1405 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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